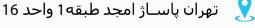






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Unit: mm

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type ( $\pi$ -MOS VI)

# 2SK4107

## Switching Regulator Applications

Low drain-source ON resistance : R<sub>DS</sub> (ON) = 0. 33 Ω (typ.)

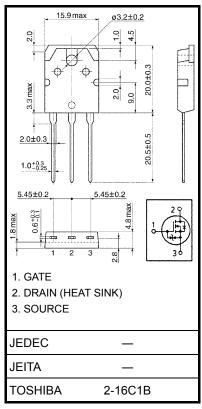
• High forward transfer admittance : |Y<sub>fs</sub>| = 8.5 S (typ.)

Low leakage current : I<sub>DSS</sub> = 100 μA (max) (V<sub>DS</sub> = 500 V)

• Enhancement mode :  $V_{th} = 2.0 \text{ to } 4.0 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$ 

#### Absolute Maximum Ratings (Ta = 25°C)

Characteri	stic	Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	500	V
Drain-gate voltage (Ro	<sub>SS</sub> = 20 kΩ)	$V_{DGR}$	500	V
Gate-source voltage		$V_{GSS}$	±30	V
Drain current	DC (Note 1)	I <sub>D</sub>	15	Α
	Pulse (Note 1)	I <sub>DP</sub>	60	Α
Drain power dissipation	n (Tc = 25°C)	PD	150	W
Single-pulse avalanche	e energy (Note 2)	E <sub>AS</sub>	765	mJ
Avalanche current		I <sub>AR</sub>	15	Α
Repetitive avalanche e	nergy (Note 3)	E <sub>AR</sub>	15	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature ra	ange	T <sub>stg</sub>	-55~150	°C



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	0.833	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	50	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 5.78 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 15 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

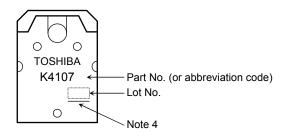
### **Electrical Characteristics (Ta = 25°C)**

Charae	cteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	V <sub>GS</sub> = ±25 V, V <sub>DS</sub> = 0 V		_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I <sub>G</sub> = ±10 μA, V <sub>DS</sub> = 0 V	±30	_	_	V
Drain cutoff curr	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0 V	_	_	100	μΑ
Drain-source br	eakdown voltage	V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V		_	_	V
Gate threshold v	voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	_	4.0	V
Drain-source O	N resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 7.0 A		0.33	0.4	Ω
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 7.0 A	4.0	8.5	_	S
Input capacitano	e	C <sub>iss</sub>		_	2450	_	
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	15	_	pF
Output capacitance		C <sub>oss</sub>	1		220	_	
Switching time	Rise time	t <sub>r</sub>	$V_{GS} \stackrel{10V}{\underset{0V}{\longrightarrow}} \stackrel{I_{D}=7A}{\underset{R_{L}=30\Omega}{\longrightarrow}} V_{out}$ $V_{DD} \stackrel{\vdots}{\rightleftharpoons} 210V$ $Duty \leq 1\%, \ t_{w}=10\mu s$	_	50	_	
	Turn-on time	t <sub>on</sub>		_	90	_	20
	Fall time	t <sub>f</sub>		_	45	_	ns ns
	Turn-off time	t <sub>off</sub>		_	175	_	
Total gate charge (gate-source plus gate-drain)		Qg		_	48	_	
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$		26	_	nC
Gate-drain ("Miller") charge		Q <sub>gd</sub>		_	22		

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	15	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	60	Α
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 15 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	I <sub>DR</sub> = 15 A, V <sub>GS</sub> = 0 V dI <sub>DR</sub> / dt = 100 A / μs	_	1050		ns
Reverse recovery charge	Q <sub>rr</sub>		_	13	_	μC

### Marking

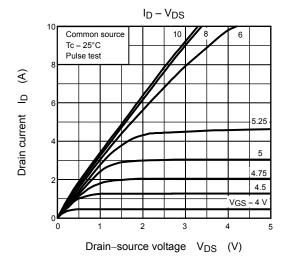


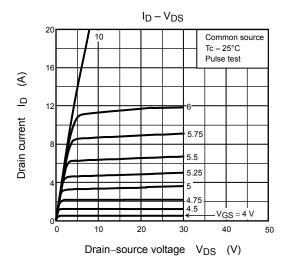
Note 4: A line under a Lot No. identifies the indication of product Labels.

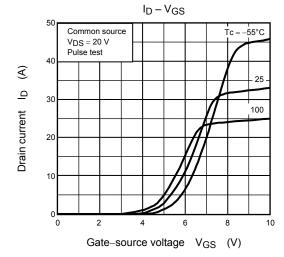
Not underlined: [[Pb]]/INCLUDES > MCV

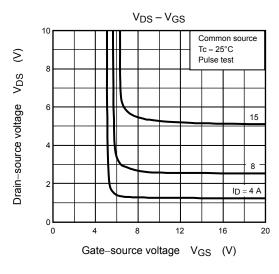
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

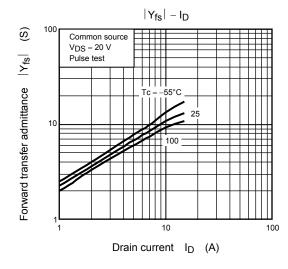
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

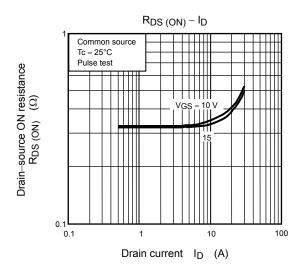




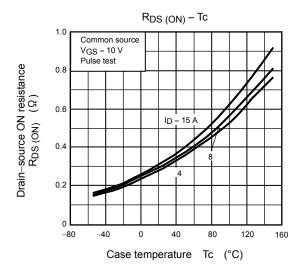


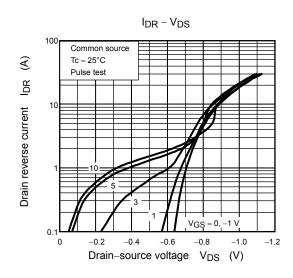


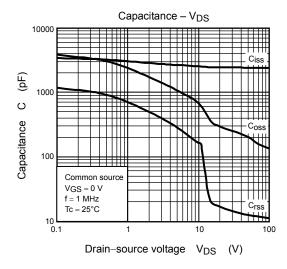


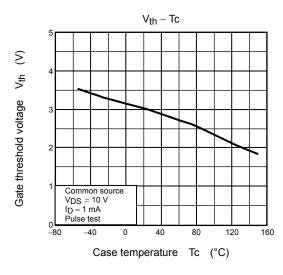


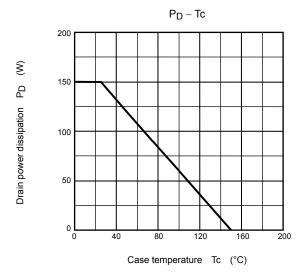
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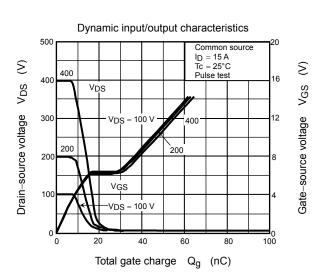




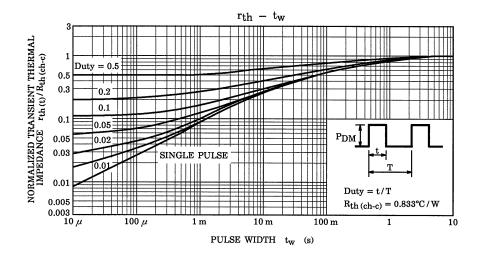




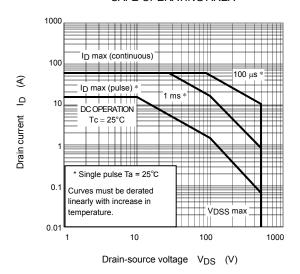


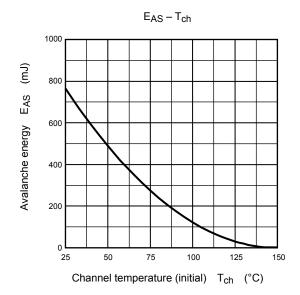


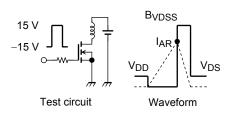
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$$\begin{aligned} &R_G = 25~\Omega \\ &V_{DD} = 90~V,~L = 5.78~mH \end{aligned} \qquad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{BVDSS}{BVDSS - V_{DD}} \right)$$

5 2009-09-29

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